

## 1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT428 (DPAK) surface mountable plastic package intended for use in applications requiring high bidirectional blocking voltage capability, high surge current capability and high thermal cycling performance.

## 2. Features and benefits

- Good bidirectional blocking voltage capability
- High surge current capability
- High thermal cycling performance
- Sensitive gate
- Surface mountable package

### 3. Applications

- Ignition circuits
- Motor control
- Protection circuits
- Voltage regulation

## 4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		-	-	500	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; $T_{mb} \le 103 \text{ °C}$ ; Fig. 1	-	-	7.5	A
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; $T_{mb} \le 103 \text{ °C}$ ; Fig. 2; Fig. 3	-	-	12	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$ ; $t_p = 10 \text{ ms}$ ; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	120	A
		half sine wave; $T_{j(init)} = 25 \text{ °C}$ ; $t_p = 8.3 \text{ ms}$	-	-	132	A
Tj	junction temperature		-	-	125	°C
Static char	acteristics	· '				
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>i</sub> = 25 °C; <u>Fig. 8</u>	_	2	5	mA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$\label{eq:DM} \begin{array}{l} V_{DM} = 335 \; V; \; T_{j} = 125 \; ^{\circ}\text{C}; \; R_{GK} = 100 \; \Omega; \\ (V_{DM} = 67\% \; of \; V_{DRM}); \; exponential \\ waveform; \; \underline{Fig. \; 13} \end{array}$	200	1000	-	V/µs

# 5. Pinning information

Table 2. F	Pinning inf	formation	-	
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	[]	A + K
2	A	anode		G sym037
3	G	gate		Symoor
mb	A	mounting base; connected to anode	DPAK (SOT428)	

# 6. Ordering information

Table 3. Ordering infor	mation					
Type number	Package					
	Name	Description	Version			
BT151S-500L	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428			

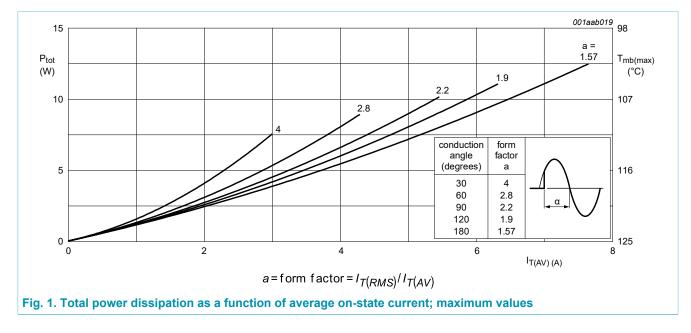


## 7. Limiting values

#### Table 4. Limiting values

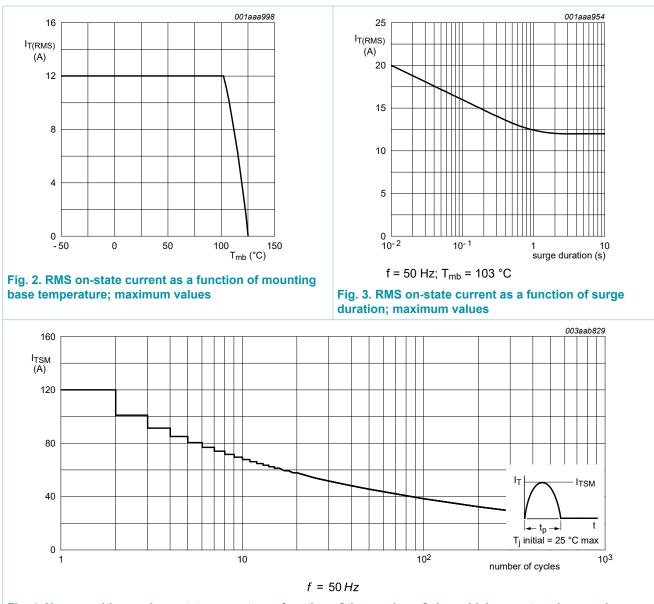
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		-	500	V
V <sub>RRM</sub>	repetitive peak reverse voltage		-	500	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>mb</sub> ≤ 103 °C; <u>Fig. 1</u>	-	7.5	А
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>mb</sub> ≤ 103 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	12	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig. 4; Fig. 5	-	120	A
		half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 8.3 ms	-	132	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN	-	72	A²s
dl <sub>T</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 10 mA	-	50	A/µs
I <sub>GM</sub>	peak gate current		-	2	А
V <sub>RGM</sub>	peak reverse gate voltage		-	5	V
P <sub>GM</sub>	peak gate power		-	5	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.5	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C



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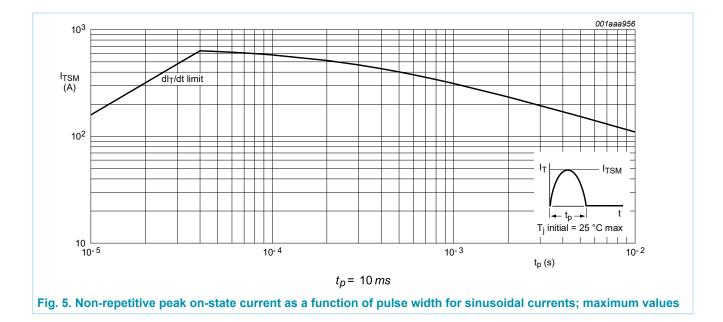
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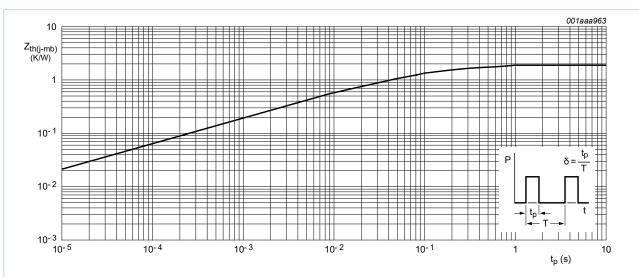


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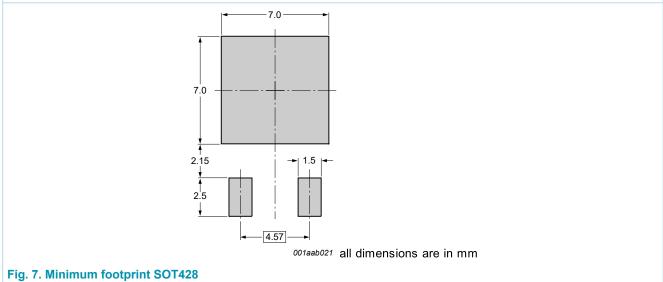


#### 8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. <u>6</u>	-	-	1.8	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	mounted on an FR4 printed-circuit board;; Fig. 7	-	75	-	K/W



#### Fig. 6. Transient thermal impedance from junction to mounting base as as function of pulse width



## 9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · · · · ·				
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	2	5	mA
IL	latching current	V <sub>D</sub> = 12 V; I <sub>G</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	10	40	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	7	20	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 23 A; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	1.4	1.75	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 12	-	0.6	1.5	V
		$V_D$ = 500 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C; Fig. 12	0.25	0.4	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 500 V; T <sub>j</sub> = 125 °C	-	0.1	0.5	mA
I <sub>R</sub>	reverse current	V <sub>R</sub> = 500 V; T <sub>j</sub> = 125 °C	-	0.1	0.5	mA
Dynamic ch	aracteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$      V_{DM} = 335 \text{ V};  \text{T}_{\text{j}} = 125 ^\circ\text{C};  \text{R}_{\text{GK}} = 100  \Omega; \\       (\text{V}_{\text{DM}} = 67\% \text{ of } \text{V}_{\text{DRM}}); \text{ exponential} \\       waveform; \underline{\text{Fig. 13}} $	200	1000	-	V/µs
		$V_{DM}$ = 335 V; T <sub>j</sub> = 125 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit; Fig. 13	50	130	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$ I_{TM} = 40 \text{ A}; \text{ V}_{\text{D}} = 500 \text{ V}; \text{ I}_{\text{G}} = 0.1 \text{ A}; \text{ dI}_{\text{G}} / \\ \text{dt} = 5 \text{ A}/\mu\text{s}; \text{ T}_{\text{J}} = 25 ^{\circ}\text{C} $	-	2	-	μs
t <sub>q</sub>	commutated turn-off time	$V_{DM}$ = 335 V; T <sub>j</sub> = 125 °C; I <sub>TM</sub> = 20 A; $V_R$ = 25 V; (dI <sub>T</sub> /dt) <sub>M</sub> = 30 A/µs; dV <sub>D</sub> / dt = 50 V/µs; R <sub>GK(ext)</sub> = 100 Ω; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> )	-	70	-	μs

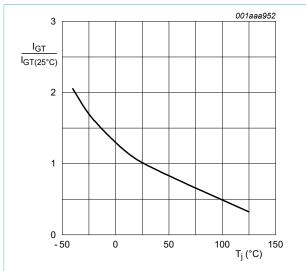
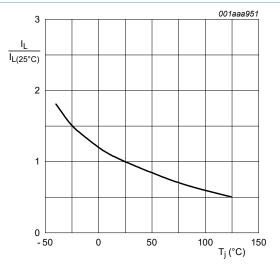


Fig. 8. Normalized gate trigger current as a function of junction temperature

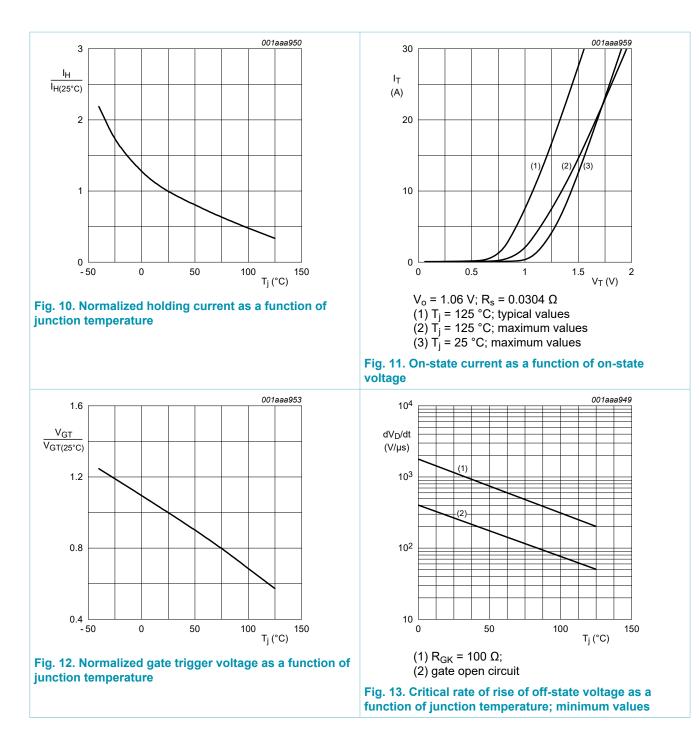




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### **10. Package outline**

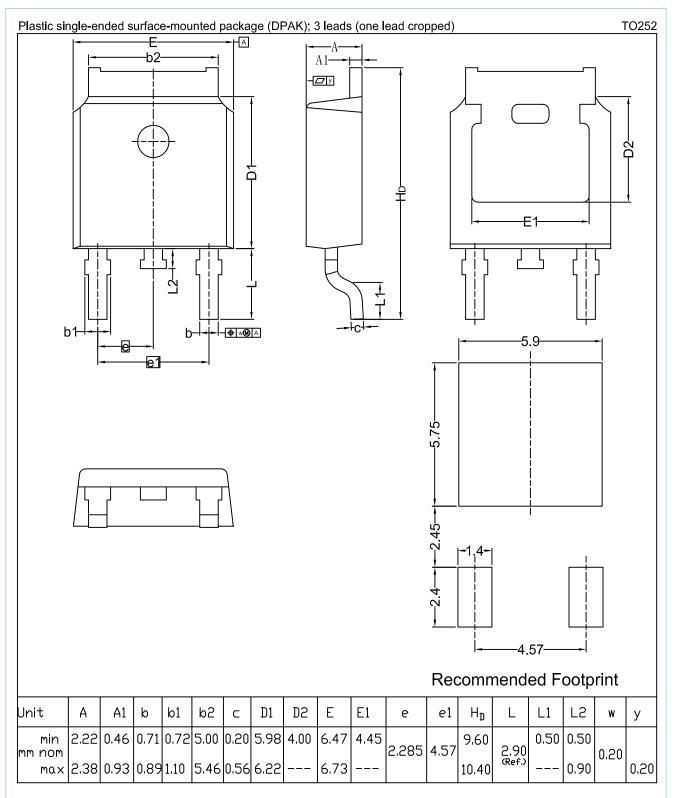


Fig. 14. Package outline DPAK (SOT428)

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Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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